



ISSN No. : 2321-9653

IJRASET

**International Journal for Research in Applied
Science & Engineering Technology**

IJRASET is indexed with Crossref for DOI-DOI : 10.22214

Website : www.ijraset.com, E-mail : ijraset@gmail.com

Certificate

It is here by certified that the paper ID : IJRASET52, entitled

Future MOSFET Devices using high-k (TiO₂) dielectric

by

Prerna Narwal

after review is found suitable and has been published in

Volume 1, Issue II, September 2013

in

*International Journal for Research in Applied Science &
Engineering Technology*

(International Peer Reviewed and Refereed Journal)

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By Prerna Narwal

Editor in Chief, IJRASET



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